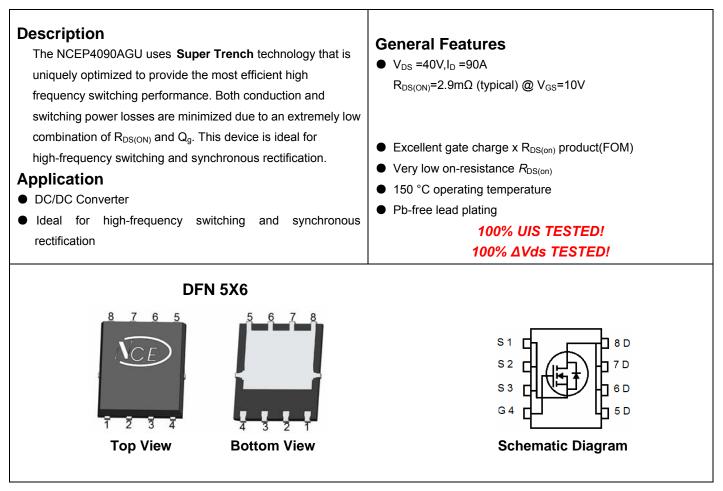


NCE N-Channel Super Trench Power MOSFET



Package Marking and Ordering Information

| Device Marking | Device | Device Package | Reel Size | Tape width | Quantity |
|----------------|-------------|----------------|-----------|------------|----------|
| P4090AGU | NCEP4090AGU | DFN5x6-8L | - | - | - |

Absolute Maximum Ratings (T_c=25[°]C unless otherwise noted)

| Symbol | Limit | Unit |
|-----------------------|--|---|
| Vds | 40 | V |
| Vgs | ±20 | V |
| Ι _D | 90 | A |
| I _D (100℃) | 63.6 | А |
| I _{DM} | 360 | А |
| PD | 70 | W |
| | 0.56 | W/℃ |
| E _{AS} | 500 | mJ |
| TJ,TSTG | -55 To 150 | °C |
| | | |
| R _{θJC} | 1.8 | °C/W |
| | VDS VGS ID ID(100°C) IDM PD EAS TJ,TSTG | VDS 40 VGS ±20 ID 90 ID(100°C) 63.6 IDM 360 PD 70 0.56 EAS TJ,TSTG -55 TO 150 |



Electrical Characteristics (T_c=25°C unless otherwise noted)

| Parameter | Symbol | Condition | Min | Тур | Max | Unit |
|------------------------------------|---------------------|---|-----|------|------|----------|
| Off Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V I _D =250µA | 40 | | - | V |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =40V,V _{GS} =0V | - | - | 1 | μA |
| Gate-Body Leakage Current | I _{GSS} | V_{GS} =±20V, V_{DS} =0V | - | - | ±100 | nA |
| On Characteristics (Note 3) | ···· | | | | | <u>.</u> |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS}=V_{GS}$, $I_{D}=250\mu A$ | 2.0 | 3.0 | 4.0 | V |
| Drain-Source On-State Resistance | R _{DS(ON)} | V _{GS} =10V, I _D =20A | - | 2.9 | 3.4 | mΩ |
| Forward Transconductance | g fs | V _{DS} =5V,I _D =20A | | 60 | - | S |
| Dynamic Characteristics (Note4) | ···· | | | | | <u>.</u> |
| Input Capacitance | C _{lss} | | - | 1695 | - | PF |
| Output Capacitance | C _{oss} | V _{DS} =20V,V _{GS} =0V, F=1.0MHz | - | 840 | - | PF |
| Reverse Transfer Capacitance | C _{rss} | | - | 34 | - | PF |
| Switching Characteristics (Note 4) | ···· | | | | | <u>.</u> |
| Turn-on Delay Time | t _{d(on)} | V _{DD} =20V,I _D =20A V _{GS} =10V,R _G =1.6Ω | - | 7.5 | - | nS |
| Turn-on Rise Time | tr | | - | 4.0 | - | nS |
| Turn-Off Delay Time | t _{d(off)} | | - | 37 | - | nS |
| Turn-Off Fall Time | t _f | | - | 7.5 | - | nS |
| Total Gate Charge | Qg | V 00V/1 00A | - | 28 | - | nC |
| Gate-Source Charge | Q _{gs} | $V_{DS}=20V, I_{D}=20A,$ | - | 9.1 | | nC |
| Gate-Drain Charge | Q _{gd} | V _{GS} =10V | - | 5.8 | | nC |
| Drain-Source Diode Characteristics | | | | • | | |
| Diode Forward Voltage (Note 3) | V _{SD} | V _{GS} =0V,I _S =20A | - | | 1.2 | V |
| Diode Forward Current (Note 2) | Is | | - | - | 90 | А |
| Reverse Recovery Time | t _{rr} | T_J = 25°C, I_F = I_S | - | 14 | - | nS |
| Reverse Recovery Charge | Qrr | di/dt = 100A/µs ^(Note3) | - | 21 | - | nC |

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, t ≤ 10 sec.

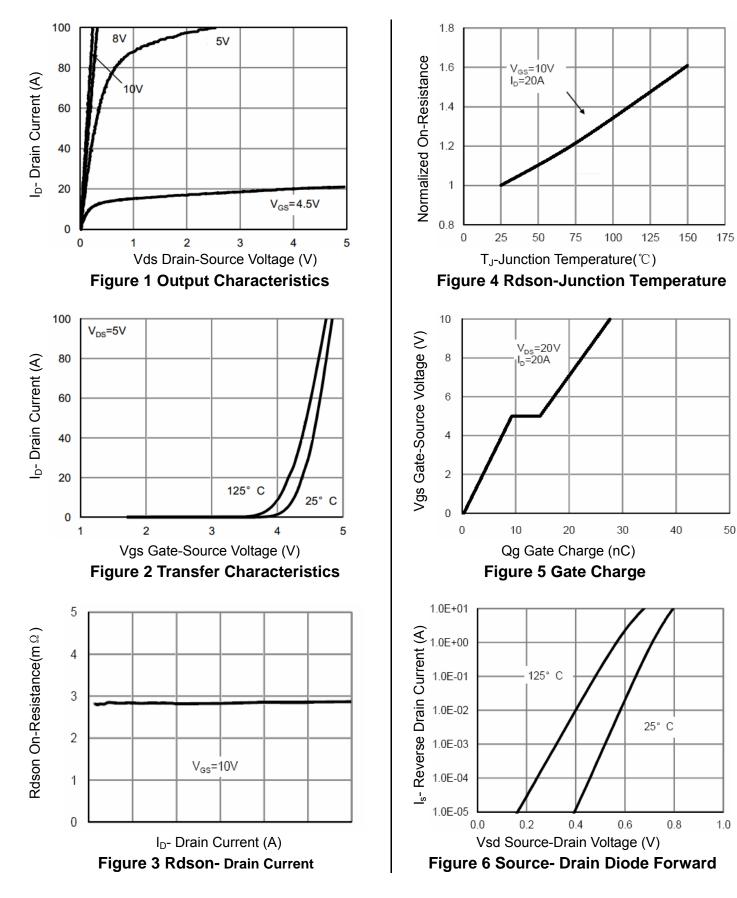
3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

4. Guaranteed by design, not subject to production

5. EAS condition : Tj=25 $^\circ \!\! \mathbb{C}$,V_DD=20V,V_G=10V,L=0.5mH,Rg=25 Ω



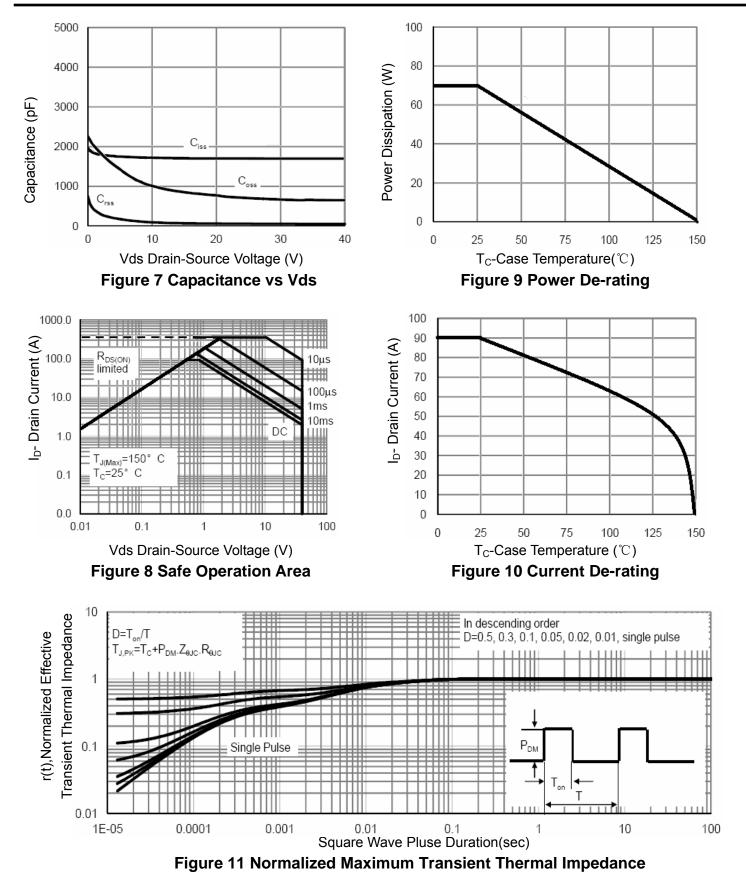
Typical Electrical and Thermal Characteristics





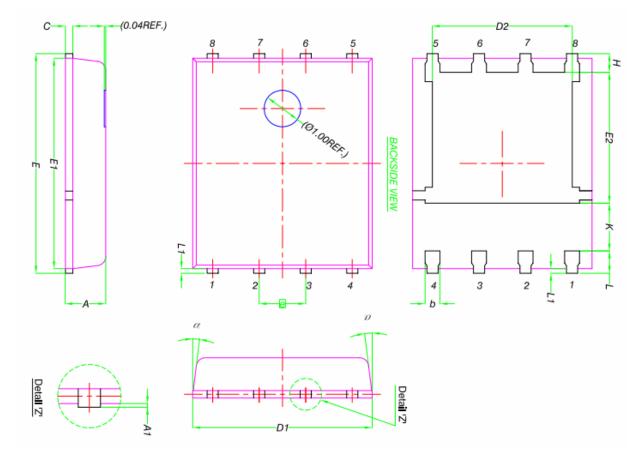
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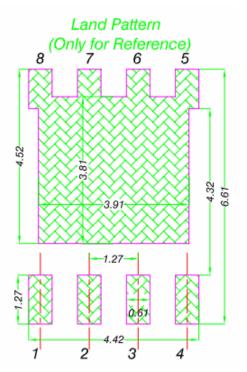




DFN5X6-8L Package Information



| | MILLIMETERS | | | | |
|------|-------------|------|------|--|--|
| DIM. | MIN. | NOM. | MAX. | | |
| А | 0.90 | 1.00 | 1.10 | | |
| A1 | 0 | - | 0.05 | | |
| b | 0.33 | 0.41 | 0.51 | | |
| С | 0.20 | 0.25 | 0.30 | | |
| D1 | 4.80 | 4.90 | 5.00 | | |
| D2 | 3.61 | 3.81 | 3.96 | | |
| E | 5.90 | 6.00 | 6.10 | | |
| E1 | 5.70 | 5.75 | 5.80 | | |
| E2 | 3.38 | 3.58 | 3.78 | | |
| е | 1.27 BSC | | | | |
| Н | 0.41 | 0.51 | 0.61 | | |
| К | 1.10 | - | - | | |
| L | 0.51 | 0.61 | 0.71 | | |
| L1 | 0.06 | 0.13 | 0.20 | | |
| α | 0° | - | 12° | | |





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